ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND, unless otherwise noted.)
Supply Voltage (V _{CC})0.3V to +6V
Output of Internal Regulator (VTRM)0.3V to (V _{CC} + 0.3V)
Input Voltage (D+, D-)0.3V to +6V
System Supply Voltage (V _L)0.3V to +6V
RCV, SUSP, VM, VP, MODE,
$\overline{\text{OE}}$, SPEED, ENUM0.3V to (V _L + 0.3V)
Short-Circuit Current (D+, D-)
to V _{CC} or GND (Note 1)Continuous
Maximum Continuous Current (all other pins)±15mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
4 x 4 UCSP (derate 7.4mW/°C above +70°C)	589mW [B16-2]
14-Pin TSSOP (derate 9.1mW/°C above +70°C)	727mW [U14-1]
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	
Lead Temperature (soldering, 10s)	+300°C
Bump Temperature (soldering) Reflow	

Note 1: External 23.7 Ω resistors connected to D+ and D-.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +4V \text{ to } +5.5V, \text{GND} = 0, \text{VTRM} = +3.0V \text{ to } +3.6V, \text{V}_L = +1.65V \text{ to } +3.6V, \text{T}_A = \text{T}_{MIN} \text{ to T}_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $V_{CC} = +5V, \text{V}_L = +2.5V, \text{T}_A = +25^{\circ}C.)$ (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
SUPPLY INPUTS (VCC, VTRM, V	/L)					•	
Regulated Supply Voltage	V _{VTRM}	Internal regulator	3.0	3.3	3.6	V	
V _L Input Range			1.65		3.60	V	
V _{CC} Input Range			4.0		5.5	V	
Operating V _{CC} Supply Current	lvcc	Full-speed transmitting/receiving at 12Mbps, C _L = 50pF on D+ and D-			8	mA	
Operating V _L Supply Current	I _{VL}	Full-speed transmitting/receiving at 12Mbps			6	mA	
Full-Speed Idle and SE0 Supply	1	Full-speed idle: $V_{D+} > 2.7V$, $V_{D-} < 0.3V$		340	450	^	
Current	IVCC(IDLE)	SE0: V _{D+} < 0.3V, V _{D-} < 0.3V		390	500	μΑ	
Static V _L Supply Current	IVL(STATIC)	Full-speed idle, SE0, or suspend mode			5	μΑ	
Suspend Supply Current	IVCC(SUSP)	$SUSP = \overline{OE} = high$			40	μΑ	
Disable-Mode Supply Current	IVCC(DIS)	V _L = GND or open			20	μΑ	
D+/D- Disable-Mode Load Current	I _{D_(DIS)}	$V_L = GND$ or open, $V_{D} = 0$ or +5.5V			5	μA	
Sharing-Mode V _L Supply Current	IVL(SHARING)	V _{CC} = GND or open, \overline{OE} = low, SUSP = high			20	μA	
D+/D- Sharing-Mode Load Current	ID_(SHARING)	V _{CC} = GND or open, V _D _ = 0 or +5.5V			20	μΑ	
LINEAR REGULATOR	•						
External Capacitor	Cout	Compensation of linear regulator	1			μF	

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +4V \text{ to } +5.5V, \text{GND} = 0, \text{VTRM} = +3.0V \text{ to } +3.6V, \text{V}_{L} = +1.65V \text{ to } +3.6V, \text{T}_{A} = \text{T}_{MIN} \text{ to T}_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $V_{CC} = +5V, \text{V}_{L} = +2.5V, \text{T}_{A} = +25^{\circ}C.)$ (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ESD PROTECTION (D+, D-)			•			
Human Body Model				±15		kV
IEC 1000-4-2 Air-Gap Discharge				±10		kV
IEC 1000-4-2 Contact Discharge				±8		kV
LOGIC-SIDE I/O						
Input High Voltage	VIH	VP, VM, SUSP, SPEED, $\overline{\text{OE}}$, MODE, ENUM	(2/3) x V _L			V
Input Low Voltage	V_{IL}	VP, VM, SUSP, SPEED, $\overline{\text{OE}}$, MODE, ENUM			0.4	V
Output High Voltage	VoH	ISOURCE = +2mA, RCV, VP, VM	V _L - 0.4			V
Output Low Voltage	VoL	I _{SINK} = -2mA, RCV, VP, VM			0.4	V
Input Leakage Current		VP , VM , $SUSP$, $ENUM$, \overline{OE} , $MODE = 0$ or V_L			±1	μΑ
USB-SIDE I/O						
Output-Voltage Low	Vold	$R_L = 1.5k\Omega$ from D+ or D- to 3.6V			0.3	V
Output-Voltage High	Vohd	$R_L = 15k\Omega$ from D+ and D- to GND	2.8		3.6	V
Input Impedance	Z _{IN}	V _D _ = 0 or +3.6V, ENUM = 0, three-state driver	1			МΩ
Single-Ended Input-Voltage High	VIH		2.0			V
Single-Ended Input-Voltage Low	VIL				8.0	V
D+, D- Receiver Hysteresis				200		mV
Driver Output Impedance	Rout		4.6		16.0	Ω
Internal Resistor	RPULLUP		1.410	1.5	1.540	kΩ
Input Common-Mode Voltage			0.8		2.5	V
Differential Input Sensitivity			200			mV

TIMING CHARACTERISTICS

 $(V_{CC} = +4V \text{ to } +5.5V, \text{GND} = 0, \text{ VTRM} = +3.0V \text{ to } +3.6V, \text{ V}_{L} = +1.65V \text{ to } +3.6V, \text{ T}_{A} = \text{T}_{MIN} \text{ to T}_{MAX}, \text{ unless otherwise noted. Typical values are at V}_{CC} = +5V, \text{V}_{L} = +2.5V, \text{T}_{A} = +25^{\circ}\text{C.})$ (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS		
SPEED INDEPENDENT TIMING CHARACTERISTICS								
OE to VP/VM Three-State Delay Disable Time	t _{PVZ}	Figures 1a and 4a			20	ns		
OE to VP/VM Delay Enable Time	tPZV	Figures 1a and 4a			25	ns		
D+/D- to RCV Propagation Delay	tpLH	C _L = 25pF, Figures 4b and 5			18	ns		
D+/D- to RCV Propagation Delay	tphL	C _L = 25pF, Figures 4b and 5			18	ns		



TIMING CHARACTERISTICS (continued)

 $(V_{CC} = +4V \text{ to } +5.5V, \text{ GND} = 0, \text{ VTRM} = +3.0V \text{ to } 3.6V, \text{ } V_{L} = +1.65V \text{ to } +3.6V, \text{ } T_{A} = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V_{CC} = +5V, \text{ } V_{L} = +2.5V, \text{ } T_{A} = +25^{\circ}\text{C.}) \text{ (Note 2)}$

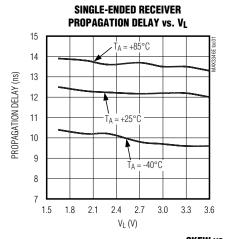
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
D+/D- to VP/VM Propagation	tpLH	C _L = 25pF, Figures 4b and 5			18	20
Delay	tphl	C _L = 25pF, Figures 4b and 5			18	ns
FULL-SPEED TIMING CHARACT	ERISTICS					
OE to Transmit Delay Enable Time	t _{PZD}	(Figures 1b, 4d)			20	ns
OE to Driver Three-State Delay Disable Time	tPDZ	(Figures1b, 4d)			20	ns
VP/VM to D+/D- Propagation	tpLH	(Figures 3, 4c)			18	
Delay (MODE = 1)	tphl	(Figures 3, 4c)			18	ns
VP to D+/D- Propagation Delay	t _{PHL0}	C _L = 50pF (Figures 2, 4c)			20	
(MODE = 0)	t _{PLH0}	C _L = 50pF (Figures 2, 4c)			20	ns
D+, D- Rise Time	t _R	$C_L = 50pF$, 10% to 90% of $IV_{OH} - V_{OL}I$	4		20	ns
D+, D- Fall Time	tF	$C_L = 50$ pF, 90% to 10% of $IV_{OH} - V_{OL}I$	4		20	ns
Rise- and Fall-Time Matching (Note 3)	t _R /t _F	C _L = 50pF	90		110	%
Output-Signal Crossover Voltage (Note 3)	VCRS	C _L = 50pF	1.3		2.0	V
LOW-SPEED TIMING CHARACTI	ERISTICS		•			•
VP/VM to D+/D- Propagation	tpLH	Figures 3 and 4c, C _L = 50pF to 600pF	30		250	20
Delay (MODE = 1)	tphL	Figures 3 and 4c, C _L = 50pF to 600pF	30		250	ns
VP to D+/D- Propagation Delay	t _{PHL0}	Figures 2 and 4c, C _L = 50pF to 600pF	30		250	
(MODE = 0)	t _{PLH0}	Figures 2 and 4c, C _L = 50pF to 600pF	30		250	ns
D+/D- Rise Time	t _R	$C_L = 50pF \text{ to } 600pF$			300	ns
D+/D- Fall Time	tF	C _L = 50pF to 600pF	75		300	ns
Rise- and Fall-Time Matching	t _R /t _F	$C_L = 50pF$ to $600pF$	80		125	%
Output-Signal Crossover Voltage	VCRS	$C_L = 50pF$ to $600pF$	1.3		2.0	V

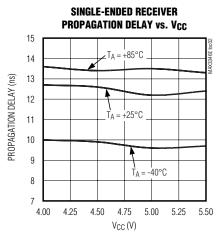
Note 2: Parameters are 100% production tested at +25°C, limits over temperature are guaranteed by design.

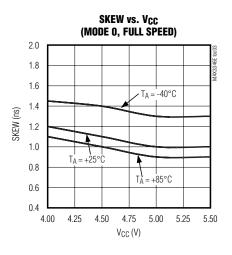
Note 3: Guaranteed by design, not production tested.

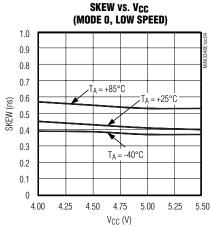
Typical Operating Characteristics

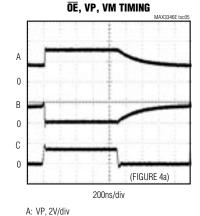
 $(V_{CC} = +5V, V_L = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$

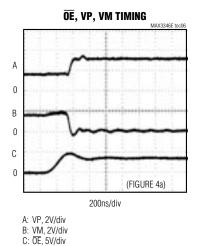


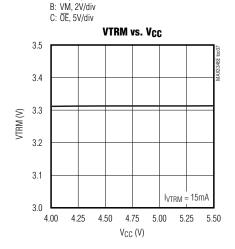






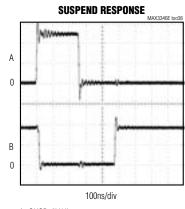


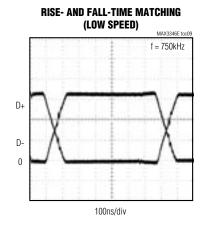


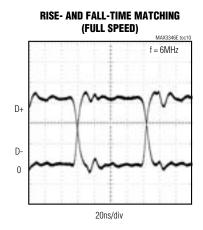


Typical Operating Characteristics (continued)

 $(V_{CC} = +5V, V_L = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$







A: SUSP, 2V/div B: RCV, 2V/div

Pin Description

Р	IN	NAME	INPUT/	FUNCTION
TSSOP	UCSP	NAME	OUTPUT	FUNCTION
1	D2	RCV	Output	Receiver Output. Single-ended CMOS output. RCV responds to the differential input on D+ and D- (see Table 3).
2	D1	VP	Input/ Output	System-Side Data Input/Output. Drive \overline{OE} high to make VP a receiver output. Drive \overline{OE} low to make VP a driver input (see Table 3).
3	C2	MODE	Input	Mode Control Input. Selects single-ended (mode zero) or differential (mode one) input for the system side when converting logic-level signals to USB-level signals. If MODE is forced high, mode one is selected. If MODE is forced low, mode zero is selected (see Table 3).
4	C1	VM	Input/ Output	System-Side Data Input/Output. Drive \overline{OE} high to make VM a receiver output. Drive \overline{OE} low to make VM a driver input (see Table 3).
5	B1	ŌĒ	Input	Output Enable. Drive $\overline{\text{OE}}$ high to enable the receiver. Drive $\overline{\text{OE}}$ low to enable the driver input.
6	A1	ENUM	Input	Enumerate Input. Drive ENUM low to disconnect the internal $1.5 k\Omega$ resistor, and enumerate the USB. With ENUM high, the internal $1.5 k\Omega$ resistor is connected to either D+ or D-, depending on the state of SPEED.

Pin Description (continued)

Р	IN	NAME	INPUT/	FUNCTION	
TSSOP	UCSP	NAME	OUTPUT	FUNCTION	
7	B2	SUSP	Input	Suspend Input. Drive SUSP low for normal operation. Force SUSP high for low-power state. In low-power state RCV is low, D+/D- are high impedance if \overline{OE} is floating, and VP/VM are active outputs.	
8	A2	SPEED	Input	USB Transmission Speed Select Input. If SPEED is forced high, full speed (12Mbps) is selected and the internal 1.5k Ω pullup resistor is connected to D+. If SPEED is forced low, low speed (1.5Mbps) is selected and the internal 1.5k Ω pullup resistor is connected to D	
9	АЗ	VCC	Power	USB-Side Power-Supply Input. Connect V _{CC} to the incoming USB power supply. Bypass V _{CC} to GND with a 1µF ceramic capacitor.	
10	A4	GND	Power	Ground	
11	B4	D-	Input/ Output	USB Differential Data Input/Output. Connect to the USB's D- signal through a 24.3Ω ±1% resistor.	
12	C4	D+	Input/ Output	USB Differential Data Input/Output. Connect to the USB's D+ signal through a 24.3Ω ±1% resistor.	
13	D4	VTRM	Power	Regulated Output Voltage. 3.3V output derived from the V_{CC} input. Bypass VTRM to GND with a 1 μ F (or more) low-ESR capacitor, such as ceramic or plastic film types.	
14	D3	VL	Power	System-Side Power-Supply Input. Connect to the system's logic-level power supply, 1.65V to 3.6V. Bypass to GND with a 0.1µF capacitor.	
_	B3, C3	_	_	Not populated. The solder sphere is omitted from these locations (see the <i>Package Information</i>).	

Detailed Description

The MAX3346E is a bidirectional transceiver that converts single-ended or differential logic-level signals to differential USB signals, and converts differential USB signals to single-ended or differential logic-level signals. The MAX3346E includes an internal $1.5k\Omega$ pullup resistor that can be connected to either D+ or D- for full-speed or low-speed operation (see the *Functional Diagram*). The MAX3346E can be energized without concern about power-supply sequencing. Additionally, the USB I/O, D+ and D-, are ESD protected to $\pm 15kV$. The MAX3346E can get its USB-side power, VCC,

directly from the USB connection, and can operate with system-side power, V_L , down to 1.65V and still meet the USB physical layer specifications. The MAX3346E supports both full-speed (12Mbps) and low-speed (1.5Mbps), USB specification 1.1 operation.

The MAX3346E has an enumerate feature that works when power is on. Driving ENUM low disconnects the internal 1.5k Ω pullup resistor from both D+ and D-, reenumerating the USB. This is useful if changes in communication protocol are required while power is applied, and while the USB cable is connected.

_Applications Information

Power-Supply Configurations

Normal Operating Mode

Connect V_L and V_{CC} to system power supplies (Table 1). Connect V_L to a +1.65V to +3.6V supply. Connect V_{CC} to a +4.0V to +5.5V supply. Alternatively, the MAX3346E can derive power from a single Li+ battery. Connect the battery to V_{CC} . VTRM remains above +3.0V for V_{CC} as low as +3.1V.

Additionally, the MAX3346E can derive power from a 3.3V ±10% voltage regulator. Connect V_{CC} and VTRM to an external +3.3V voltage regulator.

Disable Mode

Connect V_{CC} to a system power supply and leave V_L unconnected or connect to GND. D+ and D- enter a tristate mode and V_{CC} consumes less than 20µA of supply current. D+ and D- withstand external signals up to +5.5V in disable mode (Table 2).

Sharing Mode

Connect V_L to a system power supply and leave V_{CC} (or V_{CC} and V_{VTRM}) unconnected or connect to GND. D+ and D- enter a tri-state mode, allowing other circuitry to share the USB D+ and D- lines, and V_L consumes less than $20\mu A$ of supply current. D+ and D- withstand external signals up to +5.5V in sharing mode (Table 2).

Device Control

0E

 $\overline{\text{OE}}$ controls the direction of communication through the device. With $\overline{\text{OE}}$ low, the MAX3346E transfers data from the system side to the USB side. With $\overline{\text{OE}}$ high, the MAX3346E transfers data from the USB side to the system side.

ENUM

The MAX3346E allows software control of USB enumeration. USB specification 1.1 requires a $1.5 k\Omega$ pullup resistor to D+ or D- to set the transmission speed (see the SPEED section). Enumerating the USB requires removing the $1.5 k\Omega$ resistor from the circuit, and is accomplished with the MAX3346E by driving ENUM low. With ENUM high, the voltage at SPEED determines how the internal resistor is connected (see the $Functional\ Diagram$).

MODE

MODE is a control input that selects whether differential or single-ended logic signals are recognized by the system side of the MAX3346E (Table 3).

If MODE is forced high, differential input is selected. With differential input selected, outputs D+ and D- follow the differential inputs at VP and VM. If VP and VM are both forced low, an SE0 condition is forced on the USB.

Drive MODE and VM low for single-ended input mode. With single-ended input selected, the differential signal on D+ and D- is controlled by VP. If VM is high when MODE is low, D- and D+ are both low, forcing an SE0 condition.

Table 1. Power-Supply Configurations

V _{CC} (V)	VTRM (V)	V _L (V)	CONFIGURATION	NOTES
+4.0 to +5.5	+3.3 Output	+1.65 to +3.6	Normal mode	
+3.1 to +4.5	+3.3 Output	+1.65 to +3.6	Battery supply	_
+3.0 to +3.6	+3.0 to +3.6 Input	+1.65 to +3.6	Voltage regulator supply	
GND or floating	Output	+1.65 to +3.6	Sharing mode	Table 2
+3.0 to +5.5	Output	GND or floating	Disable mode	Table 2

Table 2. Disable-Mode and Sharing-Mode Configurations

INPUTS/OUTPUTS	DISABLE MODE	SHARING MODE
Vcc/VTRM	 +5V input/+3.3V output +3.3V input/+3.3V output +3.7V input/+3.3V output 	Floating or connected to GND
VL	Floating or connected to GND	+1.65V to +3.6V input
D+ and D-	High impedance	High impedance
SPEED, SUSP, OE, ENUM	High impedance	High impedance

Timing Diagrams

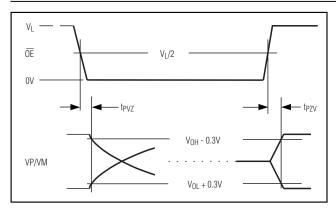


Figure 1a. Enable and Disable Timing, Receiver

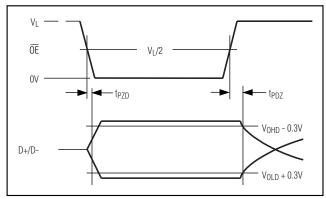


Figure 1b. Enable and Disable Timing, Transmitter

SUSP

SUSP, or suspend, is a control input. When SUSP is forced high the MAX3346E enters a low-power state. In this state, the quiescent supply current into VCC is less than $40\mu A$. In this mode, RCV is forced low, and D+ and D- are high-impedance inputs (Table 3d).

In suspend mode, data can only be transmitted with full-speed slope control.

SPEED

SPEED is a control input that selects between low-speed (1.5Mbps) and full-speed (12Mbps) USB transmission. Internally, it selects whether the 1.5k Ω pullup resistor is connected to D+ (full-speed) or D- (low-speed) (*Functional Diagram*). Force SPEED high to select full speed, or force SPEED low to select low speed.

VTRM

VTRM is the 3.3V output of the internal linear voltage regulator. The regulator is used to power the internal portions of the USB side of the MAX3346E. The VTRM

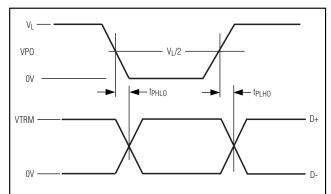


Figure 2. Mode 0 Timing

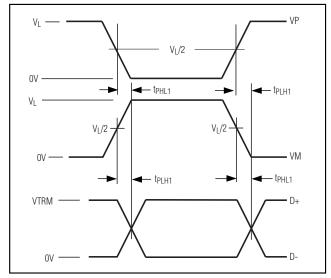


Figure 3. Mode 1 Timing

regulator's supply input is VCC. Connect a 1.0 μ F (or greater) ceramic or plastic capacitor from VTRM to GND, as close to VTRM as possible. Do not use VTRM to provide power to external circuitry.

D+ and D-

D+ and D- are the transceiver I/O connections, and are ESD protected to ±15kV using the Human Body Model, making the MAX3346E ideal for applications where a robust transmitter is required.

Vcc

Bypass VCC to GND with a $1\mu F$ capacitor. Place the $1\mu F$ capacitor as close as possible to the MAX3346E.

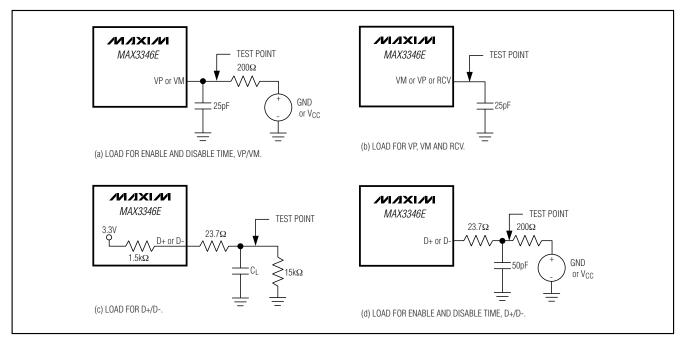


Figure 4. Test Circuits

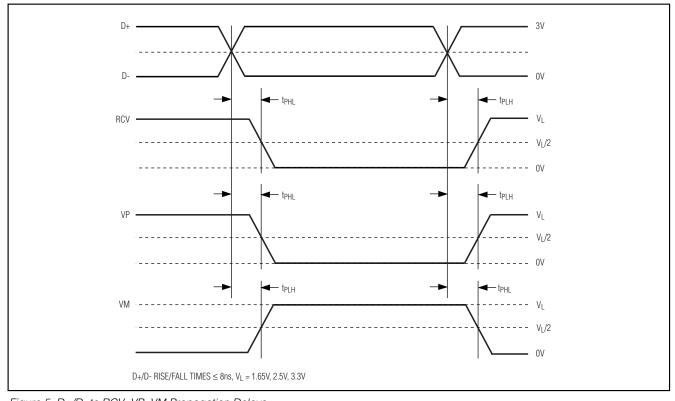


Figure 5. D+/D- to RCV, VP, VM Propagation Delays

Table 3a. Truth Table, Transmit (MODE = 0)

$\overline{\text{OE}} = 0 \text{ (TRANSMIT)}$							
IN		DECLU T					
VP	VM	D+	D-	RCV	RESULT		
0	0	0	1	0	Logic 0		
0	1	0	0	RCV*	SE0		
1	0	1	0	1	Logic 1		
1	1	0	0	X	SE0		

^{*}RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

Table 3b. Truth Table, Transmit (MODE = 1)

OE = 0 (TRANSMIT)							
IN	INPUT OUTPUT						
VP	VM	D+	D-	RCV	RESULT		
0	0	0	0	RCV*	SE0		
0	1	0	1	0	Logic 0		
1	0	1	0	1	Logic 1		
1	1	1	1	X	Undefined		

^{*}RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

Table 3c. Truth Table, Receive

DE = 1 (RECEIVE)									
INPUT			DECLUT						
D+	D-	VP	VM	RCV	RESULT				
0	0	0	0	RCV*	SE0				
0	1	0	1	0	Logic 0				
1	0	1	0	1	Logic 1				
1	1	1	1	X	Undefined				

^{*}RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

Table 3d. Function Select

SUSP	ENUMERATE	ŌĒ	D+/D-	RCV	VP/VM	FUNCTION
0	0	0	Driving	Active	High-Z	Normal driving
0	0	1	High-Z	Active	Active	Normal receiving, RPULLUP disconnected
0	1	0	Driving	Active	High-Z	Normal driving
0	1	1	High-Z	Active	Active	Normal receiving, RPULLUP connected
1	0	0 or 1	High-Z	0	Active	Suspend mode, RPULLUP disconnected
1	1	0 or 1	High-Z	0	Active	Suspend mode, RPULLUP connected

External Components

External Resistors

Two external resistors are required for USB connection, each of them from 23.7Ω ±1% to 27.4Ω ±1%, 1/2W (or greater). Place one resistor in series between D+ of the MAX3346E and D+ of the USB connector. Place the other resistor in series between D- of the MAX3346E and D- of the USB connector. The *Typical Operating Circuit* shows these connections.

External Capacitors

Four external capacitors are recommended for proper operation. Use a $0.1\mu F$ ceramic for decoupling V_L , a $1\mu F$ ceramic capacitor for decoupling V_{CC} , and a $1.0\mu F$ (or greater) ceramic or plastic filter capacitor on VTRM. Return all capacitors to GND.

Receiving Data from the USB

Data received from the USB are output to VP/VM and RCV in either of two ways, differentially or single ended. To receive data from the USB, force \overline{OE} high, and force SUSP low. Differential data arriving at D+/D- appears as differential logic signals at VP/VM, and as a single-ended logic signal at RCV. If both D+ and D- are low, then VP and VM are low, signaling an SEO condition on the bus; RCV retains the last state before SEO (see Table 3).

Transmitting Data to the USB

The MAX3346E outputs data to the USB differentially on D+ and D-. The logic driving the signals may be either differential or single ended. For sending differential logic, force MODE high, force $\overline{\text{OE}}$ and SUSP low, and apply data to VP and VM. If sending single-ended logic, force MODE, SUSP, $\overline{\text{OE}}$, and VM low, and apply data to VP. With VP low, D+ is low and D- high, resulting in a logic 0 state. With VP high, D+ is high and D-low, resulting in a logic 1 state (see Table 3).

ESD protection

To protect the MAX3346E against ESD, D+ and D- have extra protection against static electricity to protect the device up to ± 15 kV. The ESD structures withstand high ESD in all states; normal operation, suspend, and powered down. For the 15kV ESD structures to work correctly, a 1 μ F or greater capacitor must be connected from VTRM to GND.

ESD protection can be tested in various ways; the D+ and D- input/output pins are characterized for protection to the following limits:

- 1) ±15kV using the Human Body Model.
- 2) ±8kV using the Contact Discharge method specified in IEC 1000-4-2.
- 3) ±10kV using the IEC 1000-4-2 Air-Gap method.

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 6a shows the Human Body Model, and Figure 6b shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a $1.5 \mathrm{k}\Omega$ resistor.

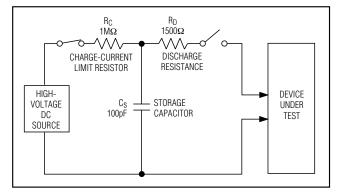


Figure 6a. Human Body ESD Test Models

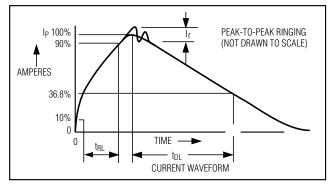


Figure 6b. Human Body Model Current Waveform

IEC 1000-4-2

The IEC 1000-4-2 standard covers ESD testing and performance of finished equipment; it does not specifically refer to integrated circuits. The MAX3346E helps to design equipment that meets Level 2 of IEC 1000-4-2, without the need for additional ESD-protection components.

The major difference between tests done using the Human Body Model and IEC 1000-4-2 is a higher peak current in IEC 1000-4-2, because series resistance is lower in the IEC 1000-4-2 model. Hence, the ESD withstand voltage measured to IEC 1000-4-2 is generally lower than that measured using the Human Body Model. Figure 7a shows the IEC 1000-4-2 model.

The Air-Gap Discharge test involves approaching the device with a charged probe. The Contact Discharge method connects the probe to the device before the probe is energized.

Machine Model

The Machine Model for ESD tests all pins using a 200pF storage capacitor and zero discharge resistance. Its objective is to emulate the stress caused by contact that occurs with handling and assembly during manufacturing. Of course, all pins require this protection during manufacturing, not just USB inputs and outputs. Therefore, after PC board assembly, the Machine Model is less relevant to I/O ports.

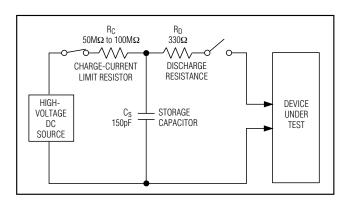
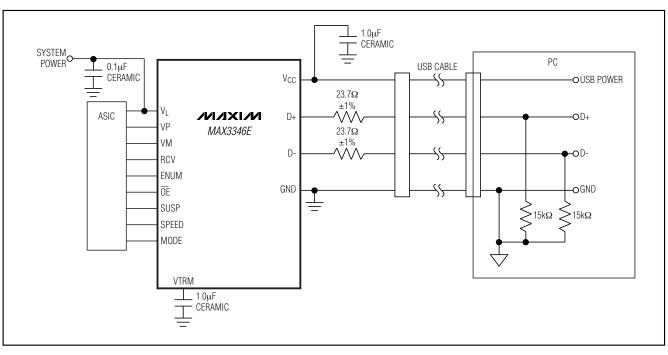


Figure 7a. IEC 1000-4-2 ESD Test Model

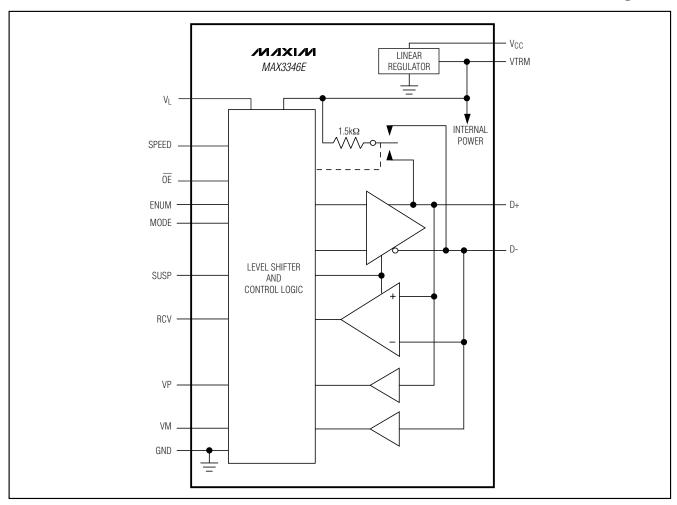
UCSP Applications Information

For the latest application details on UCSP construction, dimensions, tape carrier information, printed circuit board techniques, bump-pad layout, and recommended reflow temperature profile as well as the latest information on reliability testing results, go to the Maxim website at www.maxim-ic.com/ucsp for the Application Note, "UCSP—A Wafer-Level Chip-Scale Package."

Typical Operating Circuit



Functional Diagram

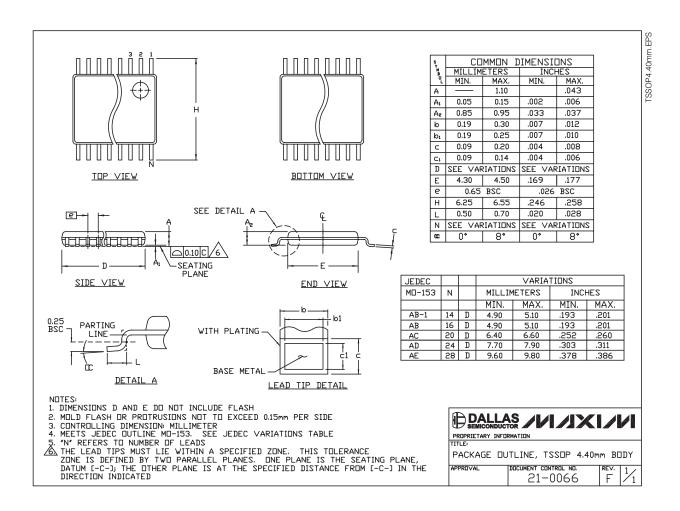


Chip Information

TRANSISTOR COUNT: 2162 PROCESS: BICMOS

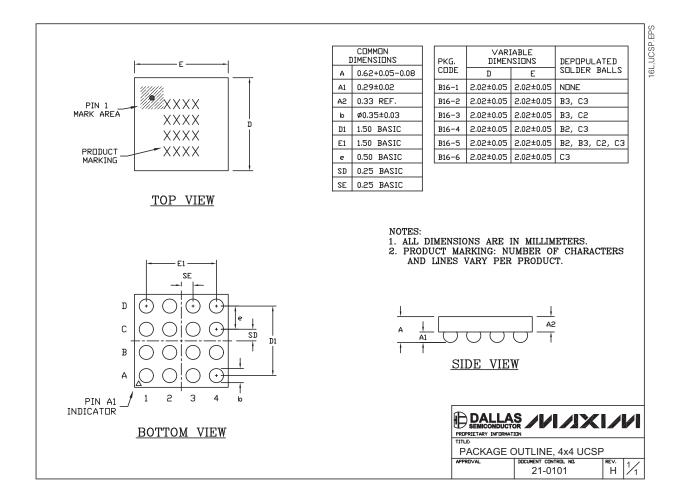
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



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